

# SYSTEMS FOR GENERATING SHORT-PULSE LASER LIGHT

## BACKGROUND OF THE INVENTION

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This invention relates to the fabrication of the lasers described below, as well as their use in various applications including micromachining, analyses by high-intensity short-pulse x-rays and medical diagnoses and treatments.

(1) Fabrication of industrially applicable short-pulse high-peak power lasers

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10 Short-pulse high-peak power lasers have a history of more than 10 years on the commercial market and yet they have not been used at industrial sites. Fig. 10A shows a conventional laser system constructed by incorporating a Ti:sapphire laser into the CPA (chirped pulse amplification) technology; as shown, the system consists of a mode-locked laser (and a pump laser), a diffraction grating paired pulse stretcher, a regenerative amplifier (and a pump laser), a master amplifier (and a pump laser), and a diffraction grating paired pulse compressor. The system

15 can produce a peak power as high as several tens of terawatts but the repetition rate is only about 10 Hz. Other disadvantages of the system include bulkiness, high cost, difficult adjustments and low reliability for consistent use over a prolonged period.

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25 Fig. 1B shows a Yb-fiber laser which consists of a fiber mode-locked laser, a fiber pulse stretcher, a fiber amplifier and a fiber pulse compressor. Although this system is compact and has repetition rates on the order of



Table 1

Function	Design considerations	Advantages(○) and disadvantages(●)	
Amplification	Laser crystal	thermal source lased on quantum efficiency	
	Nonlinear crystal	○ small thermal load due to negligible heat absorption ● suitable for producing ultra-short pulses but the system is bulky and involves difficulty in precise adjustments	
Production of shorter pulses	Diffraction grating pair	● SRS occurs and is amplified to increase system instability	
	SBS compression	Single	○ use of materials having different Raman shifts prevents SRS amplification
		Tandem	● high threshold for SRS increases vulnerability to optical damage
	SRS compression	Single	○ generation of seed light combined with amplifier lowers threshold
		Tandem	○ ultra-short pulses are difficult to generate but the system is compact ○ high Raman threshold required
	Reflection method	At full waist	○ ultra-short pulses are difficult to generate but the system is compact ○ low Raman threshold
		At half waist	

(2) Various uses of the invention

- a) non-thermal fine-machining: as a light source for precision machining of semiconductors and marking of electronic-grade glass
- 5 b) microscopes of exotic function: as a light source for multi-photon microscope
- c) lithography: as a light source for USLI fabrication
- d) x-ray fluorescence spectroscopy: enables analysis of elements in ultra-low levels
- 10 e) high intensity x-ray nondestructive analyzers: as a light source enabling the measurement of low radiation doses
- f) short-pulse x-ray diffractometer: as a light source for measuring ultra-fast structural changes
- 15 g) dental x-ray imaging apparatus: as a light source enabling imaging at low radiation dose
- h) dental scale removers: as a light source for selective removal of scale without adverse effects on the enamel
- i) high-precision x-ray imaging apparatus: as a light
- 20 source for projecting high-resolution x-rays
- j) sterilizing apparatus: as a light source for noninvasive local sterilization
- k) apparatus for removing or transplanting hair: as a light source for painless surgery
- 25 l) removal of fouling films, oxide films, plates and paints: no damage to surfaces

To produce high-peak power short-pulse laser beams, the following CPA-based methods have been used but they

have several problems from a practical viewpoint.

(1) Fiber chirping method

In this method, laser oscillation is performed with ordinary lasers and the generated pulses are compressed by eliminating chirping over fibers; the method is implemented by a Nd:YAG laser, Nd:glass laser, Nd:YLF laser, etc. Alternatively, a fiber laser is directly oscillated and the generated pulses are compressed over fibers; this method may be implemented by a Yb fiber laser which employs Yb glass. Whichever method is used, high-intensity light is passed through an extremely thin fiber, so in order to avoid optical damage, the laser power is limited and the pulse energy is no more than about 1 mJ.

(2) Grating chirping method

15 a) Ti:sapphire laser (see Fig. 10A)

This is a typical CPA-based laser and the technique which uses a pair of diffraction gratings is quite common. However, the diffraction gratings require not only a wide installation space but also precise adjustments, so the technique is too costly to be useful in general industries. In addition, the mode-locked laser as an oscillator and the regenerative amplifier also require precise adjustments. As a further problem, when a high average power is produced, the lasing crystal gives off heat in an amount corresponding to quantum efficiency and the thermal distortion from the heat generated in the crystal must be taken into account.

b) Optical parametric short-pulse laser (OPCPA, or optical

parametric CPA)

This laser performs amplification based on nonlinear effect, so the thermal load imposed on it is much smaller than what is experienced by the Ti:sapphire laser.

5 However, it still needs a mode-locked laser as an oscillator, a pulse stretcher using a diffraction grating pair, and a pulse compressor. Furthermore, the conditions for optical parametric amplification are so rigorous that efficient light emission is not easy to realize.

10 To solve these problems, the following techniques are used in the present invention.

(1) In place of the bulky diffraction grating pair, a very small nonlinear crystal is used to compress pulses. In extending and compressing pulses, precise adjustments are  
15 necessary but this requires considerable space and adds to the cost. Therefore, to minimize the required space, pulses should be compressed within a very small crystal.

(2) High power far in excess of the limit on fiber output is produced. Use of fibers in place of the diffraction  
20 grating pair has been known for years but high power cannot be produced since the passage of light through a thin fiber can cause optical damage. To cope with this problem, the present inventors developed an optical system capable of generating short pulses in high power by making use of the  
25 stimulated Raman scattering in crystal.

The Raman compression technology is known but the Raman light to be amplified usually has power with an extremely low noise level, so it has been necessary to use

extremely intense pump light but then the threshold for the generation of Raman light is high enough to increase the chance of optical damage. To avoid this problem, particularly in the case of using crystals having high

5 thresholds for the generation of Raman light, the present inventors adopted the half-waist reflection method and the tandem crystal method. In the half-waist reflection method, the crystal is so cut that the emerging laser beam has a half waist at the exit face and the crystal end face

10 is either reflection coated or fitted with a mirror to collect the scattered light, thereby lowering the threshold level. In the tandem crystal method, two crystals are used, one as an oscillator to generate faint Raman light and the other for amplifying it; as the result, the

15 threshold for the generation of Raman light is significantly lowered and, at the same time, the beam fluctuations are minimized by saturation amplification.

(3) High-power short-pulse pump light is produced. To produce short enough pulses by Raman scattering, the

20 development of a short-pulse high-power pump laser is essential. To this end, the present inventors propose a SBS-based short-pulse pump laser system which uses a tandem SBS cell method, or two different SBS cells.

In order to ensure consistent generation of intense

25 short-pulse light from one SBS cell, simultaneously occurring SRS must be prevented from circulating through the system. To meet this need, the generated SBS light is amplified by passage through the other SBS cell. Because

the two SBS cells are made of different materials, the SRS generated in the first cell is not amplified in the second cell.

- (4) Amplification is not done by the lasing medium but by a  
5 Raman crystal having a much smaller thermal load.

The biggest problem with high-power lasers is thermal load. The Ti:sapphire laser and other conventional lasers suffer loss due to quantum efficiency and this loss propagates through the crystal as heat, making it difficult  
10 to produce high power. In Raman amplification, short-pulse Raman light can be amplified efficiently without heat generation and hence high-power beams can be produced without deterioration in beam quality.

- (5) Non-CPA-based multi-stage compression

15 In CPA, the pulses generated by the mode-locked laser are first stretched, then amplified and finally compressed. This involves a lot of waste. The system of the invention starts with pulses having a duration of several hundred picoseconds, which is gradually decreased to sub-  
20 picoseconds through multiple stages, thereby achieving high efficiency and compactness. In the multi-stage approach, compression can be accomplished to a time range equivalent to the phonon life and the optical characteristics of nonlinear crystals must first be understood thoroughly.

## 25 SUMMARY OF THE INVENTION

The present invention has the following objectives.

- (1) To realize a compact, high-pulse-energy power and short-pulse laser using an amplification system that is



theoretically free from heat generation.

(2) To perform automatic correction of wave planes by generating Raman light in the presence of thermal distortion.

- 5 (3) To realize a compact system that can produce shorter pulses without using the pulse extender, pulse compressor and other devices used in CPA that are bulky and which require precise adjustments.

To attain these objects, the present inventors  
10 developed the following techniques.

a) Compressing sub-nanosecond laser pulses by the tandem SBS method using the stimulated Brillouin scattering effect.

b) Multi-stage compression of pulses to a duration as short  
15 as the phonon life (sub-picoseconds) using the stimulated Raman scattering effect.

c) Introducing seed pulses by the half-waist reflection method and the tandem crystal method for the purpose of reducing the simulated Raman scattering effect.

20 The development of these techniques requires optical data for nonlinear crystals but none of them have been available. Hence, the present inventors found by experiment the limit on optical damage and the threshold intensity of the pump laser for the generation of optical  
25 scattering in a laser field that was intense but not so strong as to cause channeling due to self-focusing.

Thus, the present invention provides a short-pulse pump laser light generator consisting essentially of:

- 1) a solid laser pumping mechanism which does not use lossy fibers but which forms parallel beams from a semiconductor laser by means of a cylindrical telescope consisting of cylindrical lenses and reshaping prism optics comprising  
5 combined prisms, with the parallel beams being condensed with a collimator lens to produce high-intensity light that can pump the active medium in the solid laser;
- 2) a pumped laser light oscillator incorporating said mechanism 1);
- 10 3) a laser light amplifier incorporating said mechanism 1); and
- 4) a SBS pulse compressor which comprises condensing optical element cells made of two different materials and which generates short-pulse laser light by the stimulated  
15 Brillouin scattering (SBS) effect.

In the generator, the pumped laser light from the oscillator is introduced into a preamplifier and amplified; the amplified light is introduced into the SBS pulse compressor and the resulting short-pulse laser light is  
20 introduced into the same preamplifier and amplified; the amplified laser light is introduced into another preamplifier, amplified and further amplified in a master amplifier, thereby producing amplified laser light having a shorter pulse duration.

25 The present invention also provides an ultra-short pulse amplified laser light generator consisting essentially of:

- a) a mechanism for producing ultra-short pulse amplified

laser light in which the short-pulse pump laser light generated by the apparatus described above is condensed by condensing optics, introduced into a Raman crystal and reflected with a reflector back into the Raman crystal to  
5 form phonon lattices;

b) a Raman light oscillator incorporating said mechanism a);

c) a laser light amplifier/compressor incorporating said mechanism a).

10 In this generator, the short-pulse pump laser light is supplied into the pump laser light amplifier and amplified; then, the Raman oscillator is pumped and the emitted light is introduced into the Raman amplifier, amplified and supplied into another Raman amplifier pumped  
15 with first Stokes radiation; the light is amplified in the second Raman amplifier, from which it is output as ultra-short pulse amplified Raman laser light.

The invention also provides:

d) an apparatus that incorporates the generator and which  
20 not only generates harmonics but also outputs compressed pulses.

#### BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 shows a laser medium pumping mechanism used in the invention;

25 Fig. 2 shows an oscillator and an amplifier that are used in the invention and which each have the laser medium pumping mechanism;

Fig. 3 shows a SBS pulse compressor used in the

invention;

Fig. 4 shows an example of a short-pulse pump laser light generator that incorporates the pumping mechanism, oscillator and amplifier of the invention;

5 Fig. 5 shows a Raman amplifier/compressor used in the invention;

Fig. 6 shows an example of an apparatus that uses the Raman amplifier/compressor to generate high-pulse-energy-power short-pulse laser light from the short-pulse pump  
10 laser light;

Fig. 7 shows Raman output energy and conversion efficiency as a function of 1064 nm input energy with several crystal lengths;

Fig. 8 shows a mechanism for obtaining optical data  
15 on Raman amplification and compression using a semiconductor laser pumped Nd:YAG laser;

Fig. 9 shows the duration of pulses in the ultra-short pulse amplified laser light obtained by the invention; and

20 Figs. 10A - 10C show three conventional mechanisms for generating high-power short-pulse laser light.

#### DETAILED DESCRIPTION OF THE INVENTION

The stated objects of the invention can be attained by the following specific means which should be taken as  
25 just one example of the way to realize the operating principles of the invention.

##### (1) Generating short-pulse pump laser light

For fabricating a compact apparatus, semiconductor

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laser light has to be condensed so that a solid laser can  
be pumped with high-intensity light having as uniform  
distribution as possible. This requires a system for  
condensing light from a semiconductor laser array that  
5 oscillates from a wide area and which has different beam  
spreads in a longitudinal and a transverse direction. An  
example of this system is shown in Fig. 1; the light from a  
semiconductor laser array is converted to parallel beams by  
passage through a cylindrical telescope consisting of  
10 concave and convex cylindrical lenses and reshaping optics  
comprising a prism array, and the parallel beams are passed  
through a conventional collimator lens so that it is  
condensed to high enough intensity to pump a solid laser  
medium (Nd:YAG). The system differs from the conventional  
15 end pumping system in that it is capable of direct pumping  
without using fibers.

The system is used to fabricate an oscillator and an  
amplifier (see Fig. 2) which can each perform axial  
pumping. Compared to the conventional transverse pumping  
20 system, the oscillator and amplifier shown in Fig. 2 can  
emit laser beams of better quality. The improved system  
arrangement is such that the semiconductor pumping light  
will not block the optical axis of the solid laser. The  
system is compact and yet the solid laser emits high-  
25 quality beams. The oscillator has a supersaturation  
absorber to produce shorter pulses.

In each of the oscillator and amplifier that are  
shown in Fig. 2, the light from a semiconductor laser 1 is

condensed by a beam distributor 2 consisting of the above-mentioned telescope and shaping optics; the condensed light passes through a resonator mirror 3 to be introduced into a laser crystal 4; by this compact system, solid laser beams  
5 of high quality are obtained from an output coupler 5. In the oscillator, a saturable absorber 6 and a telescope 7 are provided between the laser crystal 4 and the output coupler 5.

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The SBS-based short pulse generator (SBS pulse  
10 compressor) consists of two SBS cells. As Fig. 3 shows, laser light is condensed by the cell located at the farthest end to generate a diffraction grating for producing shorter pulses. Another cell is located ahead of the first cell to ensure that the light reflected from the  
15 first cell collects and compresses later coming laser light. The two cells are made of different materials (e.g.  $\text{SnCl}_4$  and  $\text{TiCl}_4$ ) that have different Raman shifts to ensure that the SRS light generated in the first (farthest) cell will not be amplified in the second cell in an intense  
20 optical field to cause system instability.

In the SBS pulse compressor shown in Fig. 3, an incident pulse 1 passes through a condensing optical element 2, SBS cell (A) 3 and a condensing optical element 4 to be condensed by SBS cell (B) 5 and the light reflected  
25 from the SBS cell (B) 5 compresses later coming laser light in the cell 3, thereby producing short-pulse laser light 6.

The elements described above (including the oscillator, amplifier and SBS pulse compressor) are

assembled to fabricate a short-pulse optical system of the type shown in Fig. 4 as an example. For efficient energy extraction, the system has additional amplifier elements that permit adequate saturation of energy. The output  
5 light (short-pulse pump laser light) is used to pump the Raman amplifier/compressor system.

The elements of the system shown in Fig. 4 are described below in detail. A semiconductor laser pumpable all-solid laser oscillator (7) has a saturable absorber  
10 and, upon pumping with a semiconductor laser, emits laser light 1 comprising pulses with a duration of a few nanoseconds. The laser light is reflected by a beam splitter (13) as indicated by 2 and enters a preamplifier (12) as indicated by 3. The amplified light 4 enters the  
15 SBS pulse compressor (10) as indicated by 5 and shortened pulses are reflected as indicated by 6. The shorter-pulse light reenters the preamplifier (12) as indicated by 3 and the amplified light 4 is reflected by a beam splitter (14) as indicated by 7, whereupon the pulse duration becomes on  
20 the order of sub-nanoseconds as indicated by 8. The shorter-pulse light enters a preamplifier (6) where it is amplified as indicated by 9; the amplified light is reflected by a beam splitter (15) and further amplified as indicated by 10. The light then enters a master amplifier  
25 (3) to be amplified as indicated by 11 and the amplified light is reflected from a mirror (1) as indicated by 12; the reflected light makes a second passage through the master amplifier (3) as indicated by 13 and short-pulse

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pump laser light having a pulse duration of sub-nanoseconds (several hundred picoseconds) is picked up from a beam splitter (16) as indicated by 14.

(2) Generating ultra-short pulse amplified laser light with  
5 Raman amplifier/compressor

Most importantly, the threshold for SRS has to be obtained without crystal loss. In addition, the diameter of the beam waist at the reflecting face of the crystal must be adequately small. It is also required that the  
10 diffraction length of the beam waist at the reflecting face of the crystal in the Raman oscillator be no more than one half the propagation distance of pulse width. Only when these conditions are met can interaction occur between the incident laser light and the forward moving diffraction  
15 grating induced in the crystal so that the backward scattered Stokes radiation is effectively amplified and compressed. The seed of the backward scattered Stokes radiation is seeded by the backward scattered Stokes radiation generated by the beams reflected from a reflector  
20 mirror provided at the terminal end of the Raman amplifier.

The Raman oscillator (Raman amplifier/compressor) is specifically shown in Fig. 5; the short-pulse pump laser light generated by the system described in the foregoing section (1) is condensed by condensing optics, introduced  
25 into a Raman crystal, reflected by a reflector, makes second entrance into the crystal and forms a reflecting diffraction grating; thereafter, ultra-short pulse amplified Raman laser light is picked up.



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The most important design consideration here is how to lower the threshold for SRS. It is easy to generate forward scattered Raman light using  $\text{CaCO}_3$ ,  $\text{LiNbO}_3$ , or  $\text{KGdWO}_4$  as the SRS crystal but if one wants backward scattering, care must be taken not to cause crystal damage.

The best way to deal with this problem is using the Raman seed in an auxiliary crystal. Unlike in the usual case of Raman light generation, SRS need not be started from spontaneous noise, so gains as high as about 50 - 60 can be obtained. In this way, the threshold for SRS can be significantly lowered compared to the value for ordinary Raman light. Specifically, two crystals are used for exciting SRS; in the first crystal, forward scattered SRS is excited and this is used as a seed for exciting backward scattered SRS in the second crystal.

Optical damage is prevented by using a system in which the short-pulse light generated in the Raman oscillator is amplified through more than one stage of Raman amplifier. The Stokes radiation from the Raman oscillator that has undergone a Stokes shift passes through the first crystal and pumps the Raman crystal at the second stage.

We now describe the system of compressing and amplifying Raman light using the Stokes radiation in the combination of the Raman oscillator and two amplifiers. Short-pulse pump laser light having a pulse width of sub-nanoseconds (several hundred picoseconds) has the wavelength of the fundamental wave in solid laser light and

it is introduced into the Raman amplifier/compressor  
consisting of crystals so as to perform simultaneous pulse  
compression and amplification. Needless to say, second and  
third harmonics of the fundamental wave can be used as pump  
5 laser light.

As shown in Fig. 6, the short-pulse pump laser light  
indicated by 1 is launched into a pump laser light  
amplifier (5) as indicated by 2, amplified as indicated by  
3 and partly reflected by a pump light distributor (8).  
10 The transmitted light 4 is polarized horizontally as  
indicated by 5 and pumps a Raman oscillator (10) as  
indicated by 6. The light from the Raman oscillator (10)  
has a pulse duration of 20 ps which is less than a tenth of  
the value for the initial pump light and the thus  
15 compressed light travels toward the first Raman amplifier  
(12).

The reflected light from the pump light distributor  
(8) travels backward as indicated by 5 and is reflected  
from a beam splitter (3) as indicated by 7 to pump a Raman  
20 amplifier (12) as indicated by 8. The light that has not  
contributed to pumping passes through the Raman amplifier  
(12) and travels toward a beam splitter (dichroic mirror)  
(14) as indicated by 10. The beam splitter (14) transmits  
only the first Stokes radiation. The non-contributory  
25 light is reflected by the beam splitter (14) to pump the  
second Raman amplifier (15) as indicated by 11.

The first Stokes radiation from the oscillator is  
amplified by the first Raman amplifier (12) and, with time

delay being taken into account, enters the second Raman amplifier (15) for further amplification. The amplified light passes through the beam splitter (dichroic mirror) (14) which transmits only the first Stokes radiation and  
5 ultra-short pulse amplified Raman laser light is output. The output light is fed into the second-stage Raman compressor and undergoes similar processes of compression to have a pulse duration as short as sub-picoseconds.

The following examples are provided for the purpose  
10 of further illustrating the invention but are in no way to be taken as limiting.

Example 1: Acquisition of Optical Data for the Compression  
of SBS Pulses

SBS compression was performed with two cells used to  
15 prevent SRS. The gain of two passes as calculated from the amplification characteristics for two passes was 2.3. As shown in the graph on the right side of Fig. 7, the pulse duration as obtained when the condensing optics in the above-described pump laser configuration had a focal length  
20 of  $f = 15$  mm was 320 ps in terms of FWHM.

Example 2: Acquisition of Optical Data for Raman  
Amplification and Compression

The threshold for SRS with  $\text{Ba}(\text{NO}_3)_2$  was measured by the beam waist reflection method using a setup of the  
25 layout shown in Fig. 8, with a mirror placed at the half beam waist. With varying values of excitation intensity, gain  $g$  was determined to be  $g \sim 10$  cm/GW with crystal length of 300 mm. Based on this data, compressing pump

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pulses of about 100 ps was assumed and the laser beam was so issued as to have a half waist at the reflecting face (exit end) of the crystal. Channeling due to self-focusing might damage the reflective coating at the exit face of the crystal and the expected intensity of the damage is about 2 - 2.5 GW/cm<sup>2</sup> for the given value of pulse duration.

Optical design must therefore be made to provide values not exceeding the calculated damage intensity. The threshold for SRS with Ba(NO<sub>3</sub>)<sub>2</sub> given such design values was about 30 kW. The multiplication factor was  $M \sim 40$ . The cross-sectional area of the laser beam at the reflecting face must be greater than  $12.7 \times 10^{-6} \text{ cm}^2$  (SRS threshold divided by damage intensity). Given this cross section, the diffraction length is 4 mm. Therefore, the crystal length must be greater than 20 mm by taking the pulse width into consideration. The compression ratio is about 5 to the extent that no optical damage occurs.

The same calculations were made for CaCO<sub>3</sub>; the diffraction length was  $\sim 2.5 \text{ cm}$  which was one half the crystal length (5 cm). The threshold for SRS as determined by the experiment was about 200 kW. The damage intensity was about 15 times as high as that of Ba(NO<sub>3</sub>)<sub>2</sub> but its threshold-power was one sixth. Therefore, given pump pulses of about 100 ps, the minimum beam diameter at the exit face of the crystal was 25 mm. Given a beam diameter  $\sim 1.6 \text{ mm}$ , the pulse compression ratio is 10 - 12.5.

When KGdWO<sub>4</sub> was pumped as the SRS crystal with 25 ps pulses, the occurrence of forward SRS was readily observed

at a gain of 4 cm/GW.

Data for the compression of initial 3 ns laser pulses through two stages are shown in Table 2.

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Table 2

Compression stage	Medium	Wavelength of pump light (nm)	Wavelength of Raman light (nm)	Threshold energy for Raman generation (mJ)	Pulse duration (ps)	Beam diameter to focal length ratio
First (SBS)	$\text{SnCl}_4$	1064	1108	1	320	1:20
Second (SRS)	$\text{Ba}(\text{NO}_3)_2$	1108	1254	0.16	20	1:20

### Example 3: Producing Shorter Pulses with Laser System

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In a semiconductor pumped by all-solid Nd:YAG laser oscillator, a Cr:YAG crystal was inserted as a supersaturation absorber and by pumping with a 100 W, 300  $\mu$ s semiconductor laser, 600  $\mu$ J laser light was produced as a sequence of 3 ns pulses. This light was amplified with a first preamplifier and compressed to a pulse duration of about 0.3 ns in a SBS pulse compressor. The compressed pulses were fed into the first preamplifier and amplified to an energy of 1.5 mJ in the form of 0.35 ns pulses. The light was further amplified in a second preamplifier to a pulse energy of 6 mJ in the form of 0.32 ns pulses. Finally, the light was subjected to 4-pass amplification in a master amplifier which was a 1200 W semiconductor laser (120 A, 300  $\mu$ s, 100 Hz), thereby producing 32 mJ short-pulse pump light having a pulse duration of 0.3 ns.

The short-pulse pump laser light ( $\lambda = 1061$  nm) was introduced into a Raman amplifier/compressor comprising a  $\text{CaCO}_3$  crystal. Fifty-five percent of the short-pulse pump light was reflected by a beam splitter. The transmitted light pumped the Raman oscillator to generate the first Stokes radiation having a pulse duration of 20 ps and a power of 0.2 mJ (see Fig. 9). The pulses in the incident pump light had been compressed to about one-fifteenth the initial duration. The Stokes radiation (1203 nm) was amplified to 2 mJ by the first Raman amplifier and further amplified to 7.8 mJ by the second Raman amplifier. The thus amplified light was output after passage through the

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dichroic mirror that transmitted only the first Stokes radiation. Eventually, the first-stage compression yielded an energy of 7.8 mJ in an efficiency of about 45%. A minimum pulse duration was 6.8 ps. The output light is  
5 supplied into the second-stage Raman compressor where it is subjected to the same compression process to have the pulse duration shortened to sub-picooseconds.

The present invention has the following advantages.

(1) Fabrication of industrial compact short-pulse, short-  
10 wavelength lasers

As mentioned in the introductory part of the specification, there is a strong demand for the use of short-pulse high-peak power lasers. The laser system using the nonlinear effect described herein contributes  
15 compactness and long-term reliability.

In order to make the apparatus of the invention into a compact, high-quality short-pulse laser, the already developed ring amplifying solid laser (patent pending) may be used as an amplifier to amplify the light from a SBS  
20 pulse compressing oscillator, with the amplified light being then introduced into a Raman amplifying and compressing system.

Taking advantage of high peak power, the apparatus of the invention can generate high-intensity, short-pulse high  
25 frequencies and x-rays, so it can provide novel light sources.

(2) Uses of the invention

1) Industrial applications using the fundamental wave



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The potential use is as light sources in machining and for multi-photon microscopes.

a. light sources in thermal fine-line machining: The high-quality, mJ-class, high repetition rate and picosecond-

5 class short-pulse laser can condense light of more than  $10^{12}$  watts per square centimeter, making it possible to perform machining without thermal effects on the surrounding area.

This presents a particularly important technology for micromachining in the semiconductor industry. It also

10 makes great contribution to the glass marking technology being practiced in the semiconductor industry, liquid-crystal industry and plasma display industry. Particularly great benefit is offered to the machining of electronic-grade glass since precision machining can be accomplished  
15 using the self-focusing effect of ultra-high power laser light in glass. In the Raman laser, a wavelength suitable for machining can be chosen by varying the amount of Raman shift with the type of Raman crystal or by shortening the wavelength via high frequencies.

20 b. light sources for multi-photon microscopes: High peak power is greatly beneficial to the multi-photon effect, so the apparatus can be used as a light source for the multi-photon microscope that can examine atoms and molecules in a particular state.

25 c. removal of corrosive films, oxide films, plates, radioactive fouling films, fouling films on the surfaces of objects of art, paint, etc. from surfaces using the ability of the high-peak power laser to remove surface

contaminants: Removal can be done without damaging the surfaces.

## 2) Industrial applications

a. light sources for lithography: Stable uv laser beams  
5 are used as a lithographic light source in the fabrication of semiconductor lasers. Excimer lasers are currently used. These gas lasers have to be improved in several points including the use of toxic gases and low  
10 reliability. The short-wavelength laser light has high intensity, so by using a nonlinear crystal, high nonlinear effect can be induced to generate stable uv light in high efficiency.

## 3) Industrial applications using x-rays:

When matter is turned into a plasma by irradiation  
15 with the high-peak power laser light, plasma x-rays are generated. If the inner shell around an atom is excited, emission-line x-rays are generated. These x-rays find utility in the following technologies.

a. x-ray fluorescence spectroscopy: Compared to the  
20 conventional method of generating x-rays by electron-beam bombardment, the high-peak power laser light produces x-rays of sufficiently high intensity to permit analysis of elements in ultra-low levels.

b. x-ray nondestructive analyzers: Compared to the  
25 conventional x-ray tube, the high-peak power laser light produces small enough spot diameters to permit analysis at high resolution.

c. x-ray diffractometer: Analyses that have been only

possible with synchrotron radiation can be performed with a very small device.

#### 4) Medical applications

Advances in laser-based technology contribute not only to noninvasive diagnosis and treatment but also to painless treatment taking advantage of the shortness of pulses.

- a. dental x-ray imaging: In the conventional dental x-ray imaging, an external x-ray source is used and this increases the imaging time and the dose of exposure. In addition, low resolution gives considerable difficulty in having correct check of the progress of root surface caries. The short-pulse laser light can be used as an x-ray source capable of overcoming these difficulties.
- b. removal of dental scale: The scale deposited on the enamel of the teeth can be removed by ablation as it is automatically distinguished from the enamel.
- c. high-precision x-ray imaging: X-rays can be generated from a focused pin point, so the motions of capillary vessels and other tissues can be imaged in high spatial resolution.
- d. sterilization: Dermatophytes such as *Trichopyton* and *Epidermophyton* can be removed by application of the short-pulse laser or metal applied to the skin can be sterilized by x-rays upon exposure to the short-pulse laser.
- e. hair removal and transplantation: Laser depilation is currently practiced but the short-pulse laser allows for completely painless depilation. A new use of this laser is

in hair transplantation; holes are made in the skin painlessly and the root of hair is transplanted into the holes.

f. removal of the horny layer: Pock marks on the face can  
5 be removed for cosmetic purposes.

g. removal of surface contaminants: The surfaces of articles covered with contaminants, plates and paint films can be selectively cleaned off.

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